Features

- Low-voltage and Standard-voltage Operation
 - $-5.0(V_{CC} = 4.5V \text{ to } 5.5V)$
 - $-2.7 (V_{CC} = 2.7V \text{ to } 5.5V)$
- User-selectable Internal Organization
 - 2K: 256 x 8 or 128 x 16
 - 4K: 512 x 8 or 256 x 16
- 3-wire Serial Interface
- Sequential Read Operation
- 2 MHz Clock Rate (5V)
- Self-timed Write Cycle (10 ms max)
- High Reliability
 - Endurance: 1 Million Write Cycles
 - Data Retention: 100 Years
- 8-lead PDIP and 8-lead JEDEC SOIC Packages

Description

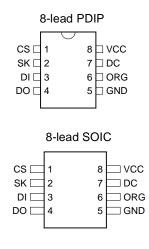
The AT93C56A/66A provides 2048/4096 bits of serial electrically erasable programmable read only memory (EEPROM) organized as 128/256 words of 16 bits each, when the ORG pin is connected to VCC and 256/512 words of 8 bits each when it is tied to ground. The device is optimized for use in many automotive applications where low power and low voltage operations are essential. The AT93C56A/66A is available in space-saving 8-lead PDIP and 8-lead JEDEC SOIC packages.

The AT93C56A/66A is enabled through the Chip Select pin (CS), and accessed via a 3-wire serial interface consisting of Data Input (DI), Data Output (DO), and Shift Clock (SK). Upon receiving a READ instruction at DI, the address is decoded and the data isclocked out serially on the data output pin DO. The WRITE cycle is completely self-timed and no separate ERASE cycle is required before WRITE. The WRITE cycle is only enabled when the part is in the ERASE/WRITE ENABLE state. When CS is brought "high" following the initiation of a WRITE cycle, the DO pin outputs the READY/BUSY status of the part.

The AT93C56A/66A is available in 4.5V to 5.5V and 2.7V to 5.5V versions.

Pin Configurations

| Pin Name | Function | | | |
|----------|-----------------------|--|--|--|
| CS | Chip Select | | | |
| SK | Serial Data Clock | | | |
| DI | Serial Data Input | | | |
| DO | Serial Data Output | | | |
| GND | Ground | | | |
| VCC | Power Supply | | | |
| ORG | Internal Organization | | | |
| DC | Don't Connect | | | |





3-wire Serial Automotive EEPROMs

2K (256 x 8 or 128 x 16)

4K (512 x 8 or 256 x 16)

AT93C56A AT93C66A

Preliminary



Rev. 3403A-SEEPR-11/03





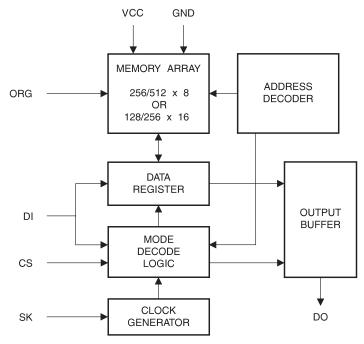
Absolute Maximum Ratings*

| Operating Temperature55°C to +125°C |
|--|
| Storage Temperature65°C to +150°C |
| Voltage on Any Pin with Respect to Ground1.0V to +7.0V |
| Maximum Operating Voltage |
| DC Output Current |

*NOTICE:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability

Block Diagram



Note: When the ORG pin is connected to VCC, the x 16 organization is selected. When it is connected to ground, the x 8 organization is selected. If the ORG pin is left unconnected and the application does not load the input beyond the capability of the internal 1 Meg ohm pullup, then the x 16 organization is selected. The feature is not available on the 1.8V devices.

Pin Capacitance⁽¹⁾

Applicable over recommended operating range from $T_A = 25$ °C, f = 1.0 MHz, $V_{CC} = +5.0$ V (unless otherwise noted).

| Symbol | bol Test Conditions | | Units | Conditions |
|------------------|--------------------------------|---|-------|----------------|
| C _{OUT} | Output Capacitance (DO) | 5 | pF | $V_{OUT} = 0V$ |
| C _{IN} | Input Capacitance (CS, SK, DI) | 5 | pF | $V_{IN} = 0V$ |

Note: 1. This parameter is characterized and is not 100% tested.

DC Characteristics

Applicable over recommended operating range from: $T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{CC} = +2.7\text{V}$ to +5.5V, (unless otherwise noted).

| Symbol | Parameter | Test Condition | | Min | Тур | Max | Unit |
|--|---|----------------------------------|----------------------------------|-----------------------|-----|----------------------------|------|
| V _{CC1} | Supply Voltage | | | 2.7 | | 5.5 | V |
| V _{CC2} | Supply Voltage | | | 4.5 | | 5.5 | V |
| | 0 | | READ at 1.0 MHz | | 0.5 | 2.0 | mA |
| I _{CC} | Supply Current | $V_{CC} = 5.0V$ | WRITE at 1.0 MHz | | 0.5 | 2.0 | mA |
| I _{SB1} | Standby Current | V _{CC} = 2.7V | CS = 0V | | 6.0 | 10.0 | μA |
| I _{SB2} | Standby Current | V _{CC} = 5.0V | CS = 0V | | 17 | 30 | μΑ |
| I _{IL} | Input Leakage | $V_{IN} = 0V \text{ to } V_{CC}$ | | | 0.1 | 1.0 | μA |
| I _{OL} | Output Leakage | $V_{IN} = 0V \text{ to } V_{CC}$ | $V_{IN} = 0V \text{ to } V_{CC}$ | | 0.1 | 1.0 | μA |
| V _{IL1} ⁽¹⁾ V _{IH1} ⁽¹⁾ | Input Low Voltage Input High Voltage | 2.7V ≤ V _{CC} ≤ 5.5V | 2.7V ≤ V _{CC} ≤ 5.5V | | | 0.8 V _{CC} + 1 | V |
| V _{OL1} | Output Low Voltage | 45)/ ()/ (55)/ | I _{OL} = 2.1 mA | | | 0.4 | V |
| V _{OH1} | Output High Voltage | $4.5V \le V_{CC} \le 5.5V$ | I _{OH} = -0.4 mA | 2.4 | | | V |
| V _{OL2} | Output Low Voltage | 4.01/ 4.1/ 4.0.71/ | I _{OL} = 0.15 mA | | | 0.2 | V |
| V _{OH2} | Output High Voltage | $1.8V \le V_{CC} \le 2.7V$ | I _{OH} = -100 μA | V _{CC} - 0.2 | | | V |

Note: 1. V_{IL} min and V_{IH} max are reference only and are not tested.





AC Characteristics

Applicable over recommended operating range from $T_A = -40$ °C to + 125 °C, $V_{CC} = As$ Specified, CL = 1 TTL Gate and 100 pF (unless otherwise noted).

| Symbol | Parameter | Test Condition | | Min | Тур | Max | Units |
|--------------------------|-------------------------------|--|--|------------|-----|------------|--------------|
| f _{SK} | SK Clock Frequency | $4.5V \le V_{CC} \le 5.5V$ $2.7V \le V_{CC} \le 5.5V$ | | 0 0 | | 2 1 | MHz |
| t _{SKH} | SK High Time | $4.5V \le V_{CC} \le 5.5V$ $2.7V \le V_{CC} \le 5.5V$ | | 250 250 | | | ns |
| t _{SKL} | SK Low Time | $4.5V \le V_{CC} \le 5.5V$ $2.7V \le V_{CC} \le 5.5V$ | | 250 250 | | | ns |
| t _{CS} | Minimum CS Low Time | $4.5V \le V_{CC} \le 5.5V$ $2.7V \le V_{CC} \le 5.5V$ | | 250 250 | | | ns |
| t _{CSS} | CS Setup Time | Relative to SK | $4.5V \le V_{CC} \le 5.5V$ $2.7V \le V_{CC} \le 5.5V$ | 50 50 | | | ns |
| t _{DIS} | DI Setup Time | Relative to SK | $4.5V \le V_{CC} \le 5.5V$ $2.7V \le V_{CC} \le 5.5V$ | 100 100 | | | ns |
| t _{CSH} | CS Hold Time | Relative to SK | | 0 | | | ns |
| t _{DIH} | DI Hold Time | Relative to SK | $4.5V \le V_{CC} \le 5.5V$ $2.7V \le V_{CC} \le 5.5V$ | 100 100 | | | ns |
| t _{PD1} | Output Delay to '1' | AC Test | $4.5V \le V_{CC} \le 5.5V$ $2.7V \le V_{CC} \le 5.5V$ | | | 250 500 | ns |
| t _{PD0} | Output Delay to '0' | AC Test | $4.5V \le V_{CC} \le 5.5V$ $2.7V \le V_{CC} \le 5.5V$ | | | 250 500 | ns |
| t _{SV} | CS to Status Valid | AC Test | $4.5V \le V_{CC} \le 5.5V$ $2.7V \le V_{CC} \le 5.5V$ | | | 250 250 | ns |
| t _{DF} | CS to DO in High Impedance | AC Test CS = V _{IL} | $4.5V \le V_{CC} \le 5.5V$ $2.7V \le V_{CC} \le 5.5V$ | | | 100 150 | ns |
| | Weite Oak T | | | | | 10 | ms |
| t _{WP} | Write Cycle Time | | 2.7V ≤ V _{CC} ≤ 5.5V | | 3 | | ms |
| Endurance ⁽¹⁾ | 5.0V, 25°C, Page Mo | de | | 1M | | | Write Cycles |

Note: 1. This parameter is characterized and is not 100% tested.

Instruction Set for the AT93C56A and AT93C66A

| | | Ор | Addre | ess | Data | | |
|-------------|----|------|---------------------------------|---------------------------------|---------------------------------|----------------------------------|---|
| Instruction | SB | Code | x 8 | x 16 | x 8 | x 16 | Comments |
| READ | 1 | 10 | A ₈ - A ₀ | A ₇ - A ₀ | | | Reads data stored in memory, at specified address. |
| EWEN | 1 | 00 | 11XXXXXXX | 11XXXXXX | | | Write enable must precede all programming modes. |
| ERASE | 1 | 11 | A ₈ - A ₀ | A ₇ - A ₀ | | | Erase memory location A _n - A ₀ . |
| WRITE | 1 | 01 | A ₈ - A ₀ | A ₇ - A ₀ | D ₇ - D ₀ | D ₁₅ - D ₀ | Writes memory location A _n - A ₀ . |
| ERAL | 1 | 00 | 10XXXXXXX | 10XXXXXX | | | Erases all memory locations. Valid only at $V_{CC} = 4.5V$ to 5.5V. |
| WRAL | 1 | 00 | 01XXXXXXX | 01XXXXXX | D ₇ - D ₀ | D ₁₅ - D ₀ | Writes all memory locations. Valid only at $V_{CC} = 5.0V \pm 10\%$ and Disable Register cleared. |
| EWDS | 1 | 00 | 00XXXXXXX | 00XXXXXX | | | Disables all programming instructions. |

Note: The X's in the address field represent don't care values and must be clocked.

Functional Description

The AT93C56A/66A is accessed via a simple and versatile 3-wire serial communication interface. Device operation is controlled by seven instructions issued by the host processor. A valid instruction starts with a rising edge of CS and consists of a Start Bit (logic "1") followed by the appropriate Op Code and the desired memory Address location.

READ (READ): The Read (READ) instruction contains the Address code for the memory location to be read. After the instruction and address are decoded, data from the selected memory location is available at the serial output pin DO. Output data changes are synchronized with the rising edges of serial clock SK. It should be noted that a dummy bit (logic "0") precedes the 8- or 16-bit data output string. The AT93C56A/66A supports sequential read operations. The device will automatically increment the internal address pointer and clock out the next memory location as long as Chip Select (CS) is held high. In this case, the dummy bit (logic "0") will not be clocked out between memory locations, thus allowing for a continuous stream of data to be read.

ERASE/WRITE (EWEN): To assure data integrity, the part automatically goes into the Erase/Write Disable (EWDS) state when power is first applied. An Erase/Write Enable (EWEN) instruction must be executed first before any programming instructions can be carried out. Please note that once in the Erase/Write Enable state, programming remains enabled until an Erase/Write Disable (EWDS) instruction is executed or V_{CC} power is removed from the part.

ERASE (ERASE): The Erase (ERASE) instruction programs all bits in the specified memory location to the logical "1" state. The self-timed erase cycle starts once the ERASE instruction and address are decoded. The DO pin outputs the READY/BUSY status of the part if CS is brought high after being kept low for a minimum of 250 ns (t_{CS}). A logic "1" at pin DO indicates that the selected memory location has been erased, and the part is ready for another instruction.





WRITE (WRITE): The Write (WRITE) instruction contains the 8 or 16 bits of data to be written into the specified memory location. The self-timed programming cycle, t_{WP} , starts after the last bit of data is received at serial data input pin DI. The DO pin outputs the READY/BUSY status of the part if CS is brought high after being kept low for a minimum of 250 ns (t_{CS}). A logic "0" at DO indicates that programming is still in progress. A logic "1" indicates that the memory location at the specified address has been written with the data pattern contained in the instruction and the part is ready for further instructions. A READY/BUSY status cannot be obtained if the CS is brought high after the end of the self-timed programming cycle, t_{WP} .

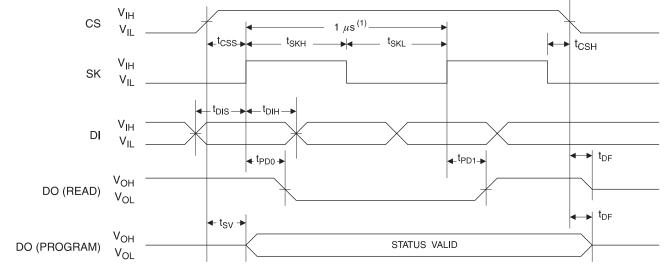
ERASE ALL (ERAL): The Erase All (ERAL) instruction programs every bit in the memory array to the logic "1" state and is primarily used for testing purposes. The DO pin outputs the READY/BUSY status of the part if CS is brought high after being kept low for a minimum of 250 ns (t_{CS}). The ERAL instruction is valid only at $V_{CC} = 5.0V \pm 10\%$.

WRITE ALL (WRAL): The Write All (WRAL) instruction programs all memory locations with the data patterns specified in the instruction. The DO pin outputs the READY/BUSY status of the part if CS is brought high after being kept low for a minimum of 250 ns (t_{CS}). The WRAL instruction is valid only at $V_{CC} = 5.0V \pm 10\%$.

ERASE/WRITE DISABLE (EWDS): To protect against accidental data disturb, the Erase/Write Disable (EWDS) instruction disables all programming modes and should be executed after all programming operations. The operation of the READ instruction is independent of both the EWEN and EWDS instructions and can be executed at any time.

Timing Diagrams

Synchronous Data Timing



Note: 1. This is the minimum SK period.

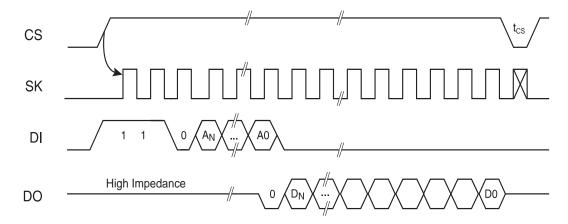
Organization Key for Timing Diagrams

| | AT93C56A (2K) | | AT93C6 | 6A (4K) |
|----------------|-------------------------------|-------------------------------|----------------|-----------------|
| I/O | x 8 x 16 | | x 8 | x 16 |
| A _N | A ₈ ⁽¹⁾ | A ₇ ⁽²⁾ | A ₈ | A ₇ |
| D _N | D ₇ | D ₁₅ | D ₇ | D ₁₅ |

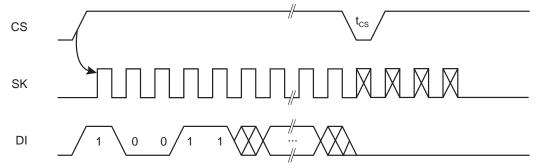
Notes: 1. A_8 is a DON'T CARE value, but the extra clock is required.

2. A_7 is a DON'T CARE value, but the extra clock is required.

READ Timing

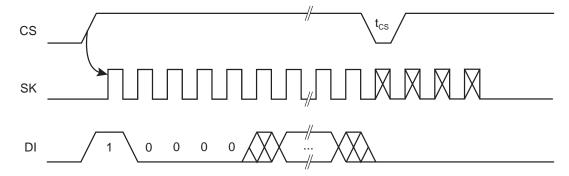


EWEN Timing

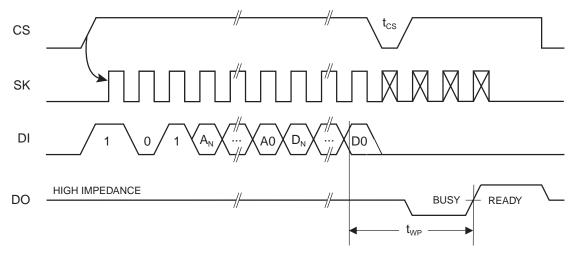




EWDS Timing

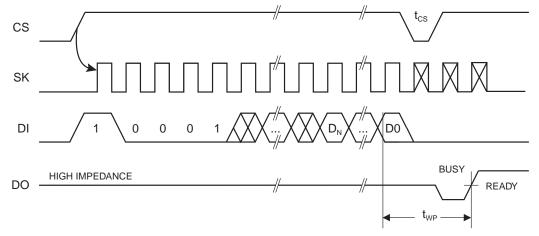


WRITE Timing



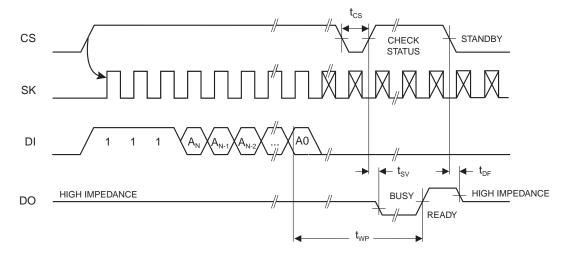
WRAL Timing⁽¹⁾

8

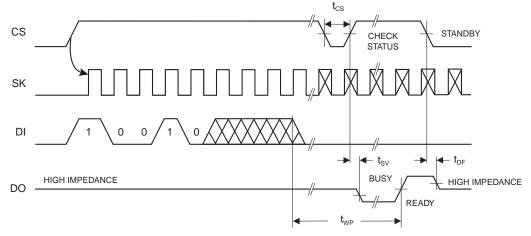


Note: 1. Valid only at $V_{CC} = 4.5V$ to 5.5V.

ERASE Timing



ERAL Timing⁽¹⁾



Note: 1. Valid only at $V_{CC} = 4.5V$ to 5.5V.



AT93C56A Ordering Information

| Ordering Code | Package | Operation Range |
|--------------------|---------|------------------|
| AT93C56A-10PA-5.0C | 8P3 | Automotive |
| AT93C56A-10SA-5.0C | 8S1 | (-40°C to 125°C) |
| AT93C56A-10PA-2.7C | 8P3 | Automotive |
| AT93C56A-10SA-2.7C | 8S1 | (-40°C to 125°C) |

| | Package Type | | | | |
|------|---|--|--|--|--|
| 8P3 | 8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP) | | | | |
| 8S1 | 8S1 8-lead, 0.150" Wide, Plastic Gull Wing Small Outline (JEDEC SOIC) | | | | |
| | Options | | | | |
| -5.0 | -5.0 Standard Operation (4.5V to 5.5V) | | | | |
| -2.7 | Low Voltage (2.7V to 5.5V) | | | | |

AT93C66A Ordering Information

| Ordering Code | Package | Operation Range |
|--------------------|----------------|------------------|
| AT93C66A-10PA-5.0C | 8P3 Automotive | |
| AT93C66A-10SA-5.0C | 8S1 | (-40°C to 125°C) |
| AT93C66A-10PA-2.7C | 8P3 | Automotive |
| AT93C66A-10SA-2.7C | 8S1 | (-40°C to 125°C) |

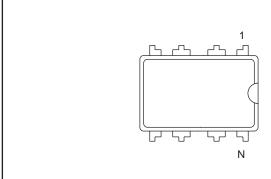
| | Package Type | | | | |
|------|---|--|--|--|--|
| 8P3 | 8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP) | | | | |
| 8S1 | 8S1 8-lead, 0.150" Wide, Plastic Gull Wing Small Outline (JEDEC SOIC) | | | | |
| | Options | | | | |
| -5.0 | -5.0 Standard Operation (4.5V to 5.5V) | | | | |
| -2.7 | Low Voltage (2.7V to 5.5V) | | | | |



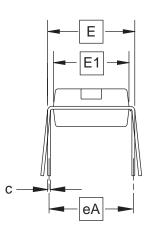


Packaging Information

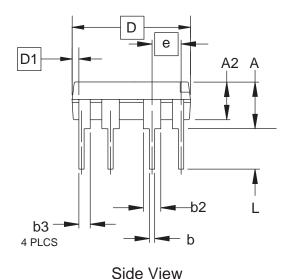
8P3 - PDIP



Top View



End View



COMMON DIMENSIONS

(Unit of Measure = inches)

| SYMBOL | MIN | NOM | MAX | NOTE |
|--------|-------|-------|-------|------|
| А | | | 0.210 | 2 |
| A2 | 0.115 | 0.130 | 0.195 | |
| b | 0.014 | 0.018 | 0.022 | 5 |
| b2 | 0.045 | 0.060 | 0.070 | 6 |
| b3 | 0.030 | 0.039 | 0.045 | 6 |
| С | 0.008 | 0.010 | 0.014 | |
| D | 0.355 | 0.365 | 0.400 | 3 |
| D1 | 0.005 | | | 3 |
| E | 0.300 | 0.310 | 0.325 | 4 |
| E1 | 0.240 | 0.250 | 0.280 | 3 |
| е | (| | | |
| eA | (| 4 | | |
| L | 0.115 | 0.130 | 0.150 | 2 |

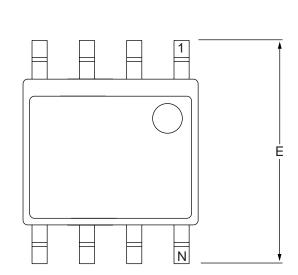
Notes:

- 1. This drawing is for general information only; refer to JEDEC Drawing MS-001, Variation BA for additional information.
- 2. Dimensions A and L are measured with the package seated in JEDEC seating plane Gauge GS-3.
- 3. D, D1 and E1 dimensions do not include mold Flash or protrusions. Mold Flash or protrusions shall not exceed 0.010 inch.
- 4. E and eA measured with the leads constrained to be perpendicular to datum.
- 5. Pointed or rounded lead tips are preferred to ease insertion.
- 6. b2 and b3 maximum dimensions do not include Dambar protrusions. Dambar protrusions shall not exceed 0.010 (0.25 mm).

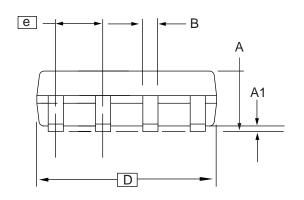
01/09/02

| | | TITLE | DRAWING NO. | REV. |
|--------------|--|--|-------------|------|
| <u>AIMEL</u> | 2325 Orchard Parkway San Jose, CA 95131 | 8P3 , 8-lead, 0.300" Wide Body, Plastic Dual In-line Package (PDIP) | 8P3 | В |

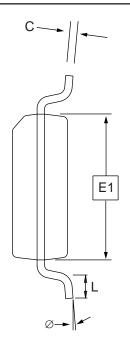
8S1 - JEDEC SOIC



Top View



Side View



End View

COMMON DIMENSIONS

(Unit of Measure = mm)

| SYMBOL | MIN | NOM | MAX | NOTE |
|--------|------|-----|------|------|
| Α | 1.35 | _ | 1.75 | |
| A1 | 0.10 | _ | 0.25 | |
| b | 0.31 | _ | 0.51 | |
| С | 0.17 | - | 0.25 | |
| D | 4.80 | - | 5.00 | |
| E1 | 3.81 | _ | 3.99 | |
| Е | 5.79 | _ | 6.20 | |
| е | | | | |
| L | 0.40 | _ | 1.27 | |
| Ø | 0° | _ | 8° | |

Note: These drawings are for general information only. Refer to JEDEC Drawing MS-012, Variation AA for proper dimensions, tolerances, datums, etc.

10/7/03



1150 E. Cheyenne Mtn. Blvd. Colorado Springs, CO 80906 **TITLE 8S1**, 8-lead (0.150" Wide Body), Plastic Gull Wing Small Outline (JEDEC SOIC)

DRAWING NO. 8S1 B





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